MC100ELT23

5V Dual Differential PECL to TTL Translator

The MC100ELT23 is a dual differential PECL to TTL translator. Because PECL (Positive ECL) levels are used, only +5 V and ground are required. The small outline 8-lead package and the dual gate design of the ELT23 makes it ideal for applications which require the translation of a clock and a data signal.

The PECL inputs are differential; therefore, the MC100ELT23 can accept any standard differential PECL input referenced from a V_{CC} of 5.0 V.

- 3.5 ns Typical Propagation Delay
- 24 mA TTL Outputs
- Flow Through Pinouts
- The 100 Series Contains Temperature Compensation
- Operating Range V_{CC} = 4.75 V to 5.25 V with GND = 0 V
- Internal Input 50 KΩ Pulldown Resistors
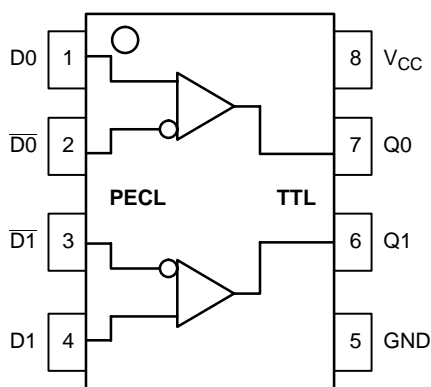- Q Output Will Default LOW with Inputs Left Open or < 1.3 V

Figure 1. 8−Lead Pinout and Logic Diagram
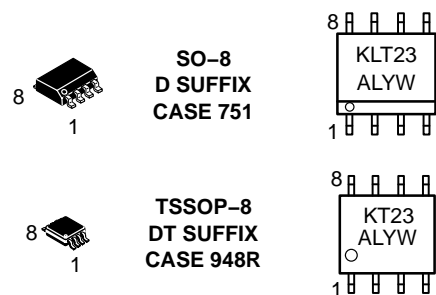(Top View)

PIN DESCRIPTION

PIN	FUNCTION
Qn	TTL Outputs
Dn, $\overline{Dn}$	PECL Differential Inputs
V_{CC}	Positive Supply
GND	Ground

ON Semiconductor®

http://onsemi.com

ORDERING INFORMATION

Device	Package	Shipping†
MC100ELT23D	SO−8	98 Units / Rail
MC100ELT23DR2	SO−8	2500 / Reel
MC100ELT23DT	TSSOP−8	98 Units / Rail
MC100ELT23DTR2	TSSOP−8	2500 / Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ATTRIBUTES

Characteristics		Value
Internal Input Pulldown Resistor		50 kΩ
Internal Input Pullup Resistor		N/A
ESD Protection	Human Body Model Machine Model	> 2 KV > 400 V
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)		Level 1
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in
Transistor Count		91
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test		

1. For additional information, see Application Note AND8003/D.

MAXIMUM RATINGS (Note 2)

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V_{CC}	Power Supply	GND = 0 V		7	V
V_I	Input Voltage	GND = 0 V	$V_I \leq V_{CC}$	0 to 6	V
T_A	Operating Temperature Range			–40 to +85	°C
T_{stg}	Storage Temperature Range			–65 to +150	°C
θ_{JA}	Thermal Resistance (Junction–to–Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction–to–Case)	Standard Board	8 SOIC	41 to 44	°C/W
θ_{JA}	Thermal Resistance (Junction–to–Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction–to–Case)	Standard Board	8 TSSOP	41 to 44 ± 5%	°C/W
T_{sol}	Wave Solder	< 2 to 3 sec @ 248°C		265	°C

2. Maximum Ratings are those values beyond which device damage may occur.

PECL INPUT DC CHARACTERISTICS V_{CC} = 5.0 V; GND = 0.0 V (Note 3)

Symbol	Characteristic	–40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V_{IH}	Input HIGH Voltage (Single–Ended) (Note 5)	3835		4120	3835		4120	3835		4120	mV
V_{IL}	Input LOW Voltage (Single–Ended)	3190		3525	3190		3525	3190		3525	mV
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 4)	2.2		5.0	2.2		5.0	2.2		5.0	V
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5			0.5			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

3. Input parameters vary 1:1 with V_{CC}. V_{CC} can vary ± 0.25 V.
4. V_{IHCMR} min varies 1:1 with GND, V_{IHCMR} max varies 1:1 with V_{CC}.
5. TTL output R_L = 500 Ω to GND.

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TTL OUTPUT DC CHARACTERISTICS V_{CC} = 4.75V to 5.25V; T_A = −40°C to 85°C

Symbol	Characteristic	Condition	Min	Typ	Max	Unit
V_{OH}	Output HIGH Voltage	I_{OH} = −3.0 mA	2.4		(Note 6)	V
V_{OL}	Output LOW Voltage	I_{OL} = 24 mA			0.5	V
I_{CCH}	Power Supply Current			23	33	mA
I_{CCL}	Power Supply Current			26	36	mA
I_{OS}	Output Short Circuit Current		−150		−60	mA

6. Max level is V_{CC} − 0.7 V by design.

AC CHARACTERISTICS V_{CC}= 5.0 V; GND= 0.0 V (Note 7 and Note 8)

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f_{max}	Maximum Toggle Frequency					100					MHz
t_{JITTER}	Random Clock Jitter (RMS)					35					ps
t_{PLH}	Propagation Delay @ 1.5 V	2.0		5.5	2.0		5.5	2.0		5.5	ns
t_{PHL}	Propagation Delay @ 1.5 V	2.0		5.5	2.0		5.5	2.0		5.5	ns
V_{PP}	Input Swing (Note 9)	200		1000	200		1000	200		1000	mV
t_r/t_f	Output Rise Time (10–90%) Output Fall Time (10–90%)					1.6 1.1					ns ns

7. V_{CC} can vary ± 0.25 V.
8. TTL output R_L = 500 Ω to GND, and C_L = 20 pF to GND. Refer to Figure 2.
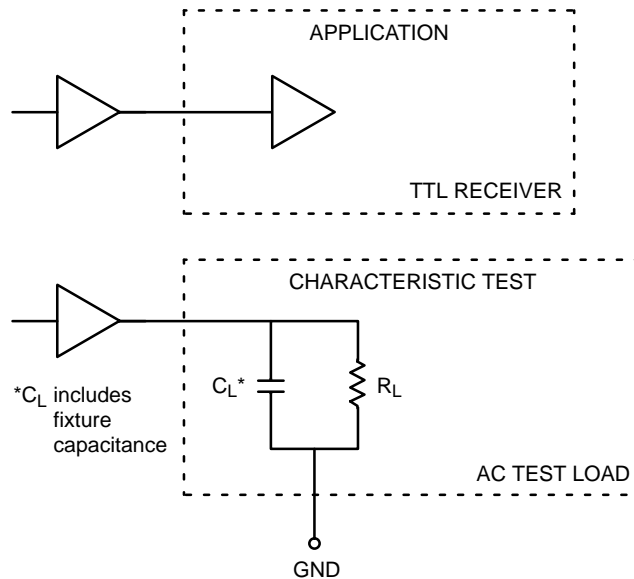9. V_{PP}(min) is the minimum input swing for which AC parameters are guaranteed. The device has a DC gain of ≈ 40.

**Figure 2. TTL Output Loading Used for Device Evaluation**

Resource Reference of Application Notes

AN1404	–	ECLinPS Circuit Performance at Non−Standard V_{IH} Levels
AN1405	–	ECL Clock Distribution Techniques
AN1406	–	Designing with PECL (ECL at +5.0 V)
AN1503	–	ECLinPS I/O SPICE Modeling Kit
AN1504	–	Metastability and the ECLinPS Family
AN1560	–	Low Voltage ECLinPS SPICE Modeling Kit
AN1568	–	Interfacing Between LVDS and ECL
AN1596	–	ECLinPS Lite Translator ELT Family SPICE I/O Model Kit
AN1650	–	Using Wire−OR Ties in ECLinPS Designs
AN1672	–	The ECL Translator Guide
AND8001	–	Odd Number Counters Design
AND8002	–	Marking and Date Codes
AND8020	–	Termination of ECL Logic Devices
AND8090	–	AC Characteristics of ECL Devices

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PACKAGE DIMENSIONS

SO–8
D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751–07
ISSUE AA
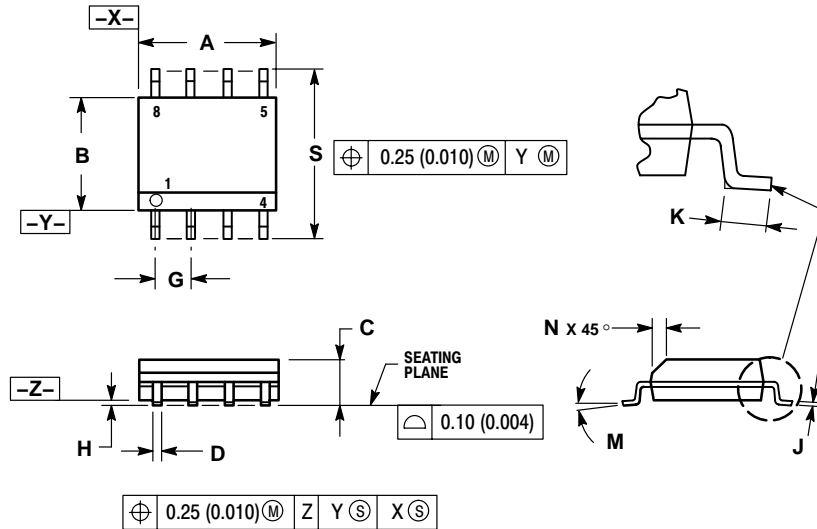
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

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PACKAGE DIMENSIONS

TSSOP−8
DT SUFFIX
PLASTIC TSSOP PACKAGE
CASE 948R−02
ISSUE A

8x **K** REF

⊕ | 0.10 (0.004) Ⓜ | T | U Ⓢ | V Ⓢ

△ | 0.15 (0.006) | T | U Ⓢ

2x **L/2**

L

8 · 5

B
−U−

PIN 1
IDENT ◦ 1 · 4

△ | 0.15 (0.006) | T | U Ⓢ

A
−V−

0.25 (0.010)

M

F

DETAIL E

C

△ | 0.10 (0.004)

−T− SEATING
PLANE

D **G**

DETAIL E

−W−
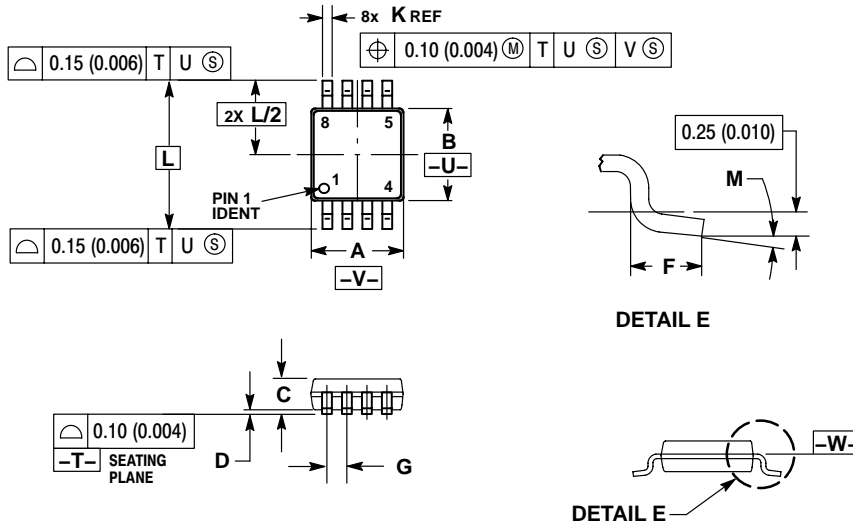
NOTES:
1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65 BSC		0.026 BSC	
K	0.25	0.40	0.010	0.016
L	4.90 BSC		0.193 BSC	
M	0 °	6 °	0 °	6 °